

N-channel 40 V, 6.0 mΩ logic level MOSFET in LFPAK33

29 January 2019

Product data sheet

1. General description

Automotive qualified logic level N-channel MOSFET in an LFPAK33 package using Trench 9 TrenchMOS technology. This product has been designed and qualified to AEC-Q101 for use in high performance automotive applications.

2. Features and benefits

- Fully automotive qualified to AEC-Q101 at 175 °C
- Trench 9 superjunction technology:
- · Low power losses, high power density
- LFPAK copper clip package technology:
 - High robustness and reliability
 - Gull wing leads for high manufacturability and AOI
- Repetitive avalanche rated

3. Applications

- 12 V automotive systems
- · Powertrain, chassis, body and infotainment applications
- Medium/Low power motor drive
- DC-DC systems
- LED lighting

4. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------|----------------------------------|--|-----|-----|-----|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | - | 40 | V |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u> | [1] | - | - | 50 | А |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | | - | - | 70 | W |
| Static char | acteristics | · | | · | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 20 A; T _j = 25 °C; Fig. 11 | | 3.4 | 4.9 | 6 | mΩ |
| Dynamic cl | haracteristics | | | | | _ | |
| Q _{GD} | gate-drain charge | I_D = 20 A; V_{DS} = 20 V; V_{GS} = 4.5 V; Fig. 13; Fig. 14 | | - | 2.9 | 5.8 | nC |
| Source-dra | in diode | | | | | | |
| Q _r | recovered charge | $I_{S} = 20 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$ $\text{V}_{DS} = 20 \text{ V}$ | | - | 17 | - | nC |

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| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------|-----------|--|--|-----|------|-----|------|
| S | | $I_{S} = 20 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 20 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 17}$ | | - | 0.65 | - | |

[1] 50A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|--------------------|----------------|
| 1 | S | source | | D. |
| 2 | S | source | | |
| 3 | S | source | | G_U |
| 4 | G | gate | | mbb076 S |
| mb | D | Mounting base; connected to drain | LFPAK33 (SOT1210) | |

6. Ordering information

| Table 3. Ordering information | | | | | | | | |
|-------------------------------|---------|--|---------|--|--|--|--|--|
| Type number Package | | | | | | | | |
| | Name | Description | Version | | | | | |
| BUK9M6R0-40H | LFPAK33 | Plastic, single ended surface mounted package (LFPAK33); 8 leads; 0.65 mm pitch | SOT1210 | | | | | |

7. Marking

| Table 4. Marking codes | | | | |
|------------------------|--------------|--|--|--|
| Type number | Marking code | | | |
| BUK9M6R0-40H | 96H040 | | | |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|---|-----|-----|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | 40 | V |
| V _{GS} | gate-source voltage | DC; T _j ≤ 175 °C | | -10 | 16 | V |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | | - | 70 | W |
| ID | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u> | [1] | - | 50 | А |
| | | V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u> | | - | 50 | А |
| I _{DM} | peak drain current | pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3 | | - | 311 | А |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| Tj | junction temperature | | | -55 | 175 | °C |
| Source-drai | n diode | | | | | |

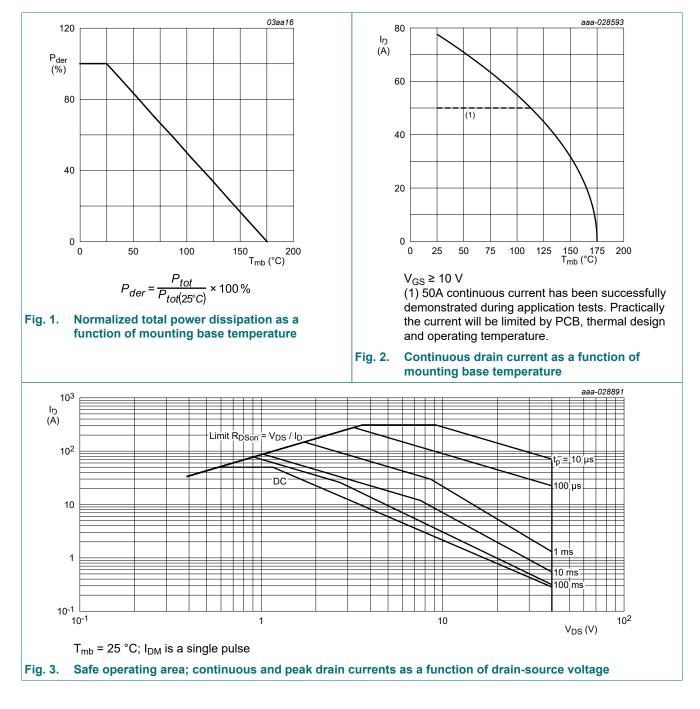
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| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|---|---------|-----|-----|------|
| I _S | source current | T _{mb} = 25 °C | | - | 50 | А |
| I _{SM} | peak source current | pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$ | | - | 311 | А |
| Avalanche ruge | jedness | | | | | |
| E _{DS(AL)S} | non-repetitive drain- source avalanche energy | $\label{eq:ld} \begin{array}{l} I_{D} = 50 \; A; \; V_{sup} \leq \; 40 \; V; \; R_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; V; \; T_{j(init)} = 25 \; ^{\circ}C; \; unclamped; \\ \hline Fig. \; \frac{4}{} \end{array}$ | [2] [3] | - | 37 | mJ |

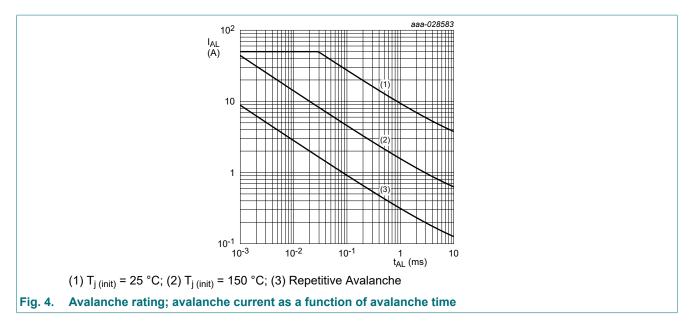
[1] 50A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

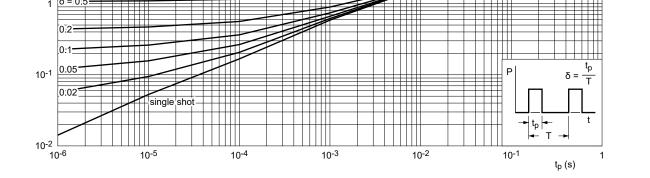


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9. Thermal characteristics

| Table 6. Therma | al characteristics | | | | | |
|--------------------------------------|---|---------------|-----|------|----------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | Fig. <u>5</u> | - | 1.91 | 2.14 | K/W |
| 10 Z _{th(j-mb)} (K/W) | | | | aa. | a-028584 | |
| 1 δ.=:0.5 | 5 | | | | | |





10. Characteristics

| Table 7. Characteristics | | | | | | | | |
|-----------------------------------|-------------------|--|-----|------|-----|------|--|--|
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit | | |
| Static characteristics | | | | | | | | |
| V _{(BR)DSS} drain-source | | I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C | 40 | 43 | - | V | | |
| | breakdown voltage | I_D = 250 µA; V_{GS} = 0 V; T_j = -40 °C | - | 40.5 | - | V | | |

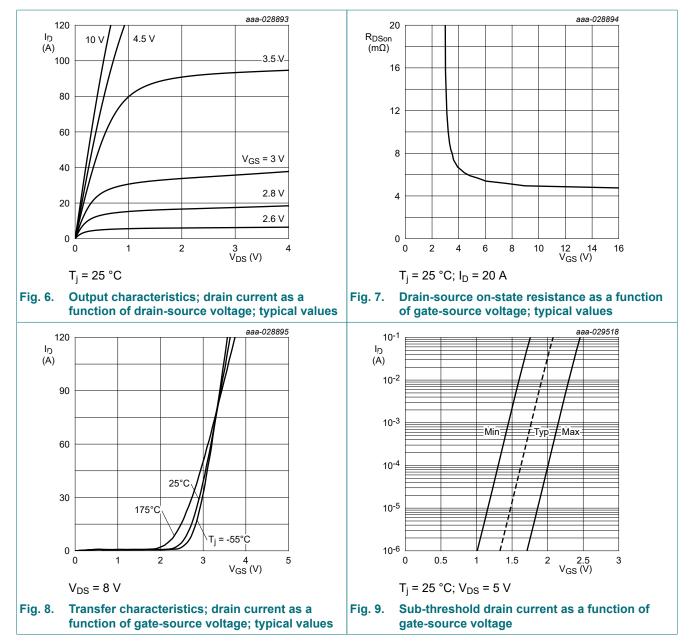
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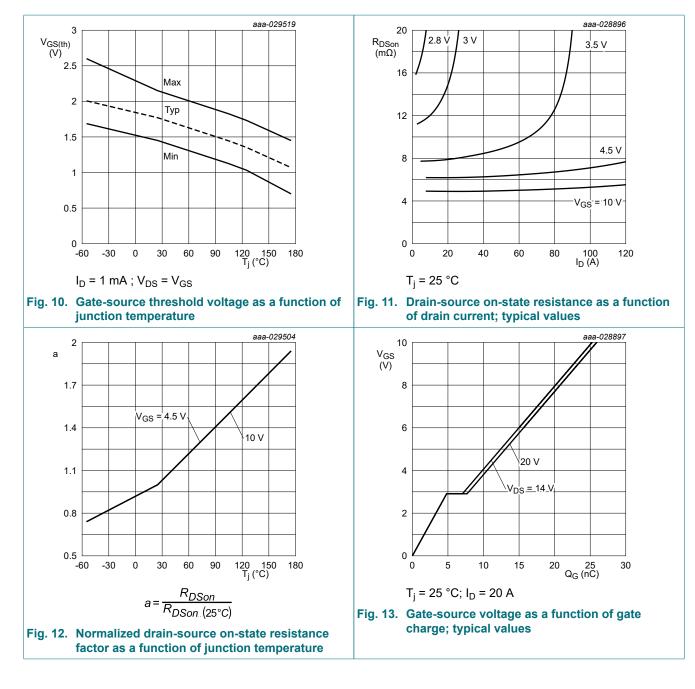
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|---------------------|---|--|------|------|------|------|
| | | $I_D = 250 \ \mu A; V_{GS} = 0 \ V; T_j = -55 \ ^{\circ}C$ | 36 | 40 | - | V |
| V _{GS(th)} | gate-source threshold voltage | I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C; <u>Fig. 9;</u> Fig. 10 | 1.45 | 1.77 | 2.15 | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 10</u> | - | - | 2.6 | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; Fig. 10 | 0.7 | - | - | V |
| I _{DSS} | drain leakage current | V _{DS} = 40 V; V _{GS} = 0 V; T _j = 25 °C | - | 0.02 | 5 | μA |
| | | V _{DS} = 16 V; V _{GS} = 0 V; T _j = 125 °C | - | 0.6 | 10 | μA |
| | | V _{DS} = 40 V; V _{GS} = 0 V; T _j = 175 °C | - | 45 | 500 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C | - | 2 | 100 | nA |
| | | V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C | - | 2 | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 20 A; T _j = 25 °C; Fig. 11 | 3.4 | 4.9 | 6 | mΩ |
| | | V _{GS} = 10 V; I _D = 20 A; T _j = 105 °C; Fig. 12 | 4.6 | 7 | 9 | mΩ |
| | | V _{GS} = 10 V; I _D = 20 A; T _j = 125 °C; Fig. 12 | 5.1 | 7.6 | 9.7 | mΩ |
| | | V _{GS} = 10 V; I _D = 20 A; T _j = 175 °C; Fig. 12 | 6.2 | 9.2 | 11.7 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 15 A; T _j = 25 °C; Fig. 11 | 4.2 | 6.1 | 7.7 | mΩ |
| | V _{GS} = 4.5 V; I _D = 15 A; T _j = 105 °C; Fig. 12 | 5.7 | 8.7 | 11.6 | mΩ | |
| | V _{GS} = 4.5 V; I _D = 15 A; T _j = 125 °C; Fig. 12 | 6.3 | 9.4 | 12.4 | mΩ | |
| | | V _{GS} = 4.5 V; I _D = 15 A; T _j = 175 °C; Fig. 12 | 7.7 | 11.3 | 15 | mΩ |
| R _G | gate resistance | f = 1 MHz; T _j = 25 °C | 0.3 | 0.8 | 2 | Ω |
| Dynamic ch | aracteristics | | I | - | _ | |
| Q _{G(tot)} | total gate charge | $I_{D} = 20 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 13; Fig. 14 | - | 26 | 36 | nC |
| | | I _D = 20 A; V _{DS} = 20 V; V _{GS} = 4.5 V; | - | 12 | 18 | nC |
| Q _{GS} | gate-source charge | Fig. 13; Fig. 14 | - | 4.8 | 7.2 | nC |
| Q _{GD} | gate-drain charge |] [| - | 2.9 | 5.8 | nC |
| C _{iss} | input capacitance | V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; | - | 1764 | 2470 | pF |
| C _{oss} | output capacitance | T _j = 25 °C; <u>Fig. 15</u> | - | 452 | 633 | pF |
| C _{rss} | reverse transfer capacitance | | - | 66 | 145 | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = 20 V; R _L = 1 Ω; V _{GS} = 4.5 V; | - | 18 | - | ns |
| t _r | rise time | $R_{G(ext)} = 5 \Omega$ | - | 25 | - | ns |
| t _{d(off)} | turn-off delay time |] [| - | 15 | - | ns |
| t _f | fall time | | - | 12 | - | ns |
| Source-drai | in diode | · | · | | | |
| V _{SD} | source-drain voltage | I _S = 20 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 16</u> | - | 0.85 | 1.2 | V |
| t _{rr} | reverse recovery time | $I_{S} = 20 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$ $V_{DS} = 20 \text{ V}; \text{ Fig. 17}$ | - | 23 | - | ns |
| Q _r | recovered charge | I_{S} = 20 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V; V _{DS} = 20 V | - | 17 | - | nC |

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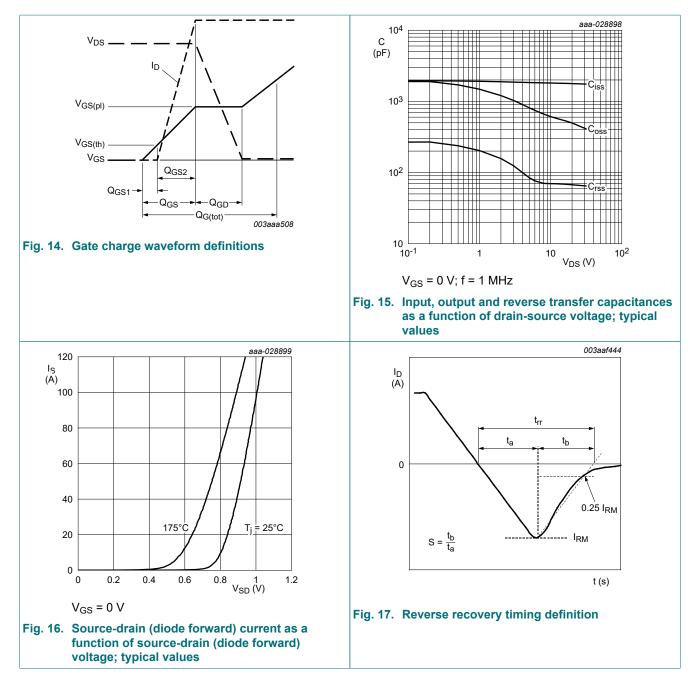
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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|-----------------|---|-----|------|-----|------|
| S | softness factor | $ I_{S} = 20 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{ V}_{DS} = 20 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 17} $ | - | 0.65 | - | |
| | | $ I_{S} = 20 \text{ A}; dI_{S}/dt = -500 A/\mu \text{s}; V_{GS} = 0 \text{V}; \\ V_{DS} = 20 \text{V}; \text{T}_{\text{j}} = 25 ^{\circ}\text{C}; \text{Fig. } 17 \\ $ | - | 0.43 | - | |



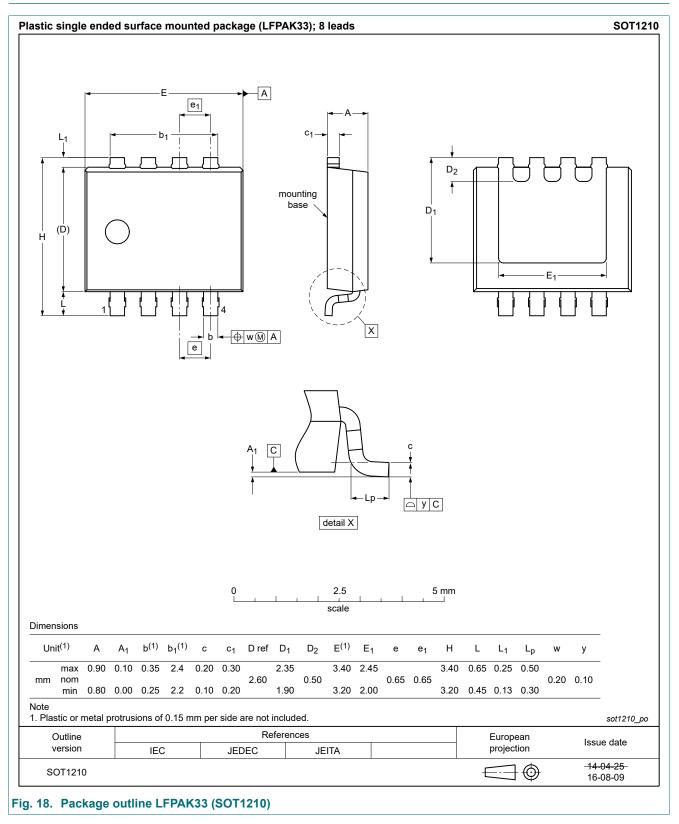


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11. Package outline



12. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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